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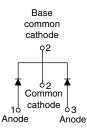
Vishay Semiconductors

Hyperfast Rectifier, 2 x 15 FRED Pt®





TO-220AB



TO-220 FULL-PAK



VS-30CTH02PbF VS-30CTH02-N3

VS-30CTH02FPPbF VS-30CTH02FP-N3

PRODUCT SUMMARY					
Package	TO-220AB, TO-220FP				
I _{F(AV)}	2 x 15 A				
V _R	200 V				
V _F at I _F	1.05 V				
t _{rr} typ.	See Recovery table				
T _J max.	175 °C				
Diode variation	Common cathode				

FEATURES

- Hyperfast recovery time
- Low forward voltage drop
- 175 °C operating junction temperature
- Low leakage current
- Fully isolated package (V_{INS} = 2500 V_{RMS})
- UL E78996 pending
- Compliant to RoHS Directive 2002/95/EC
- Designed and qualified according to JEDEC-JESD47
- Halogen-free according to IEC 61249-2-21 definition (-N3 only)

DESCRIPTION/APPLICATIONS

200 V series are the state of the art hyperfast recovery rectifiers specifically designed with optimized performance of forward voltage drop and hyperfast recovery time.

The planar structure and the platinum doped life time control, guarantee the best overall performance, ruggedness and reliability characteristics.

These devices are intended for use in the output rectification stage of SMPS, UPS, DC/DC converters as well as freewheeling diode in low voltage inverters and chopper motor drives.

Their extremely optimized stored charge and low recovery current minimize the switching losses and reduce over dissipation in the switching element and snubbers.

ABSOLUTE MAXIMUM RATINGS							
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS		
Peak repetitive reverse voltage		V _{RRM}		200	V		
	per diode	_	T _C = 159 °C	- 15 30	- A		
Average rectified forward current	(FULL-PAK) per diode		T _C = 125 °C				
	per device						
Non-repetitive peak surge current		I _{FSM}	T _J = 25 °C	200			
Operating junction and storage temperatures		T _J , T _{Stg}		- 65 to 175	°C		

ELECTRICAL SPECIFICATIONS ($T_J = 25 \ ^{\circ}C$ unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS	
Breakdown voltage, blocking voltage	V _{BR} , V _R	I _R = 100 μA	200	-	-		
Forward voltage	V _F	I _F = 15 A	-	0.92	1.05	V	
		I _F = 15 A, T _J = 125 °C	-	0.78	0.85		
Reverse leakage current		$V_R = V_R$ rated	-	-	10		
neverse leakage current	I _R	$T_J = 125 \text{ °C}, V_R = V_R \text{ rated}$	-	5	300	μA	
Junction capacitance	CT	V _R = 200 V	-	57	-	pF	
Series inductance	L _S	Measured lead to lead 5 mm from package body	-	8	-	nH	

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e3 RoHS

COMPLIANT

HALOGEN

FREE

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DYNAMIC RECOVERY CHARACTERISTICS ($T_C = 25$ °C unless otherwise specified)								
PARAMETER	SYMBOL	TEST CO	MIN.	TYP.	MAX.	UNITS		
Reverse recovery time		$I_F = 1 \text{ A}, dI_F/dt = 50$	A/μs, V _R = 30 V	-	-	35		
	+	I _F = 1 A, dI _F /dt = 100 A/μs, V _R = 30 V		-	-	30		
	t _{rr}	T _J = 25 °C	$I_{\rm F} = 15 {\rm A}$	-	26	-	ns	
		T _J = 125 °C		-	40	-		
Dook rooovery ourrent	1	T _J = 25 °C	dl _F /dt = 200 A/µs V _B = 160 V	-	2.8	-	А	
Peak recovery current	I _{RRM}	T _J = 125 °C		-	6.0	-	~	
Reverse recovery charge	Q _{rr}	T _J = 25 °C		-	37	-	nC	
		T _J = 125 °C		-	120	-		

THERMAL - MECHANICAL SPECIFICATIONS								
PARAMETER		SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS	
Maximum junction ar temperature range	nd storage	T _J , T _{Stg}		- 65	-	175	°C	
Thermal resistance,	per diode	P	Mounting surface, flat, smooth and greased	-	-	1.1	°C/W	
junction to case	(FULL-PAK) per diode	R _{thJC}		-	-	3.5	0/11	
Marking device			Case style TO-220AB	30CTH02				
			Case style TO-220 FULL-PAK	30CTH02FP				

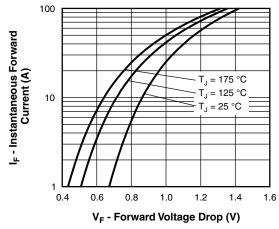


Fig. 1 - Typical Forward Voltage Drop Characteristics

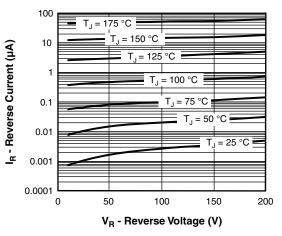


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage



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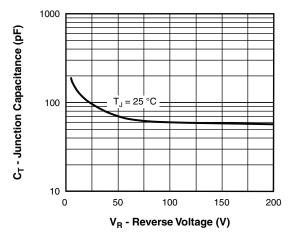


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

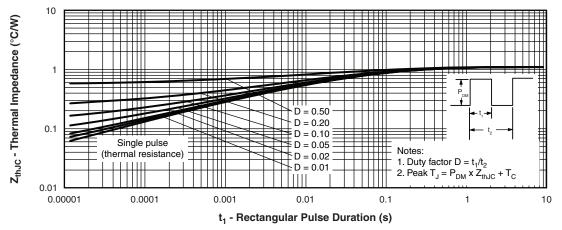


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics

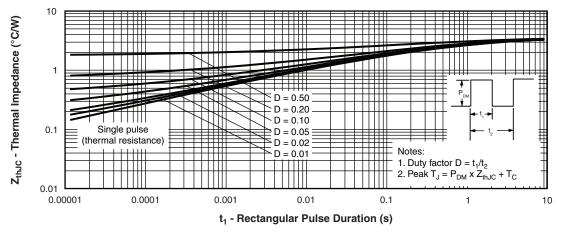
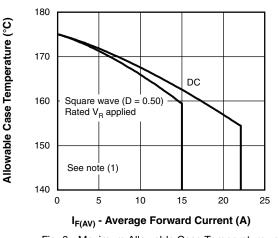


Fig. 5 - Maximum Thermal Impedance ZthJC Characteristics (FULL-PAK)

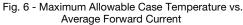
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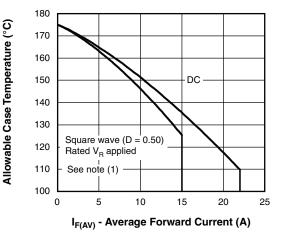
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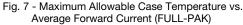
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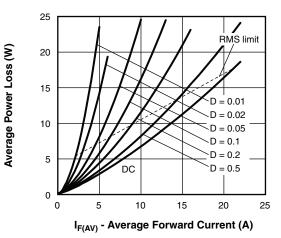
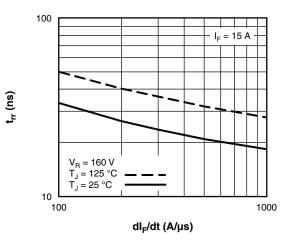
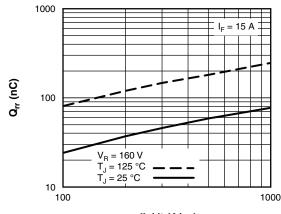


Fig. 8 - Forward Power Loss Characteristics







dl_F/dt (A/μs) Fig. 10 - Typical Stored Charge vs. dl_F/dt

Note

⁽¹⁾ Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$;

Pd = Forward power loss = I_{F(AV)} x V_{FM} at (I_{F(AV)}/D) (see fig. 8); Pd_{REV} = Inverse power loss = V_{R1} x I_R (1 - D); I_R at V_{R1} = Rated V_R

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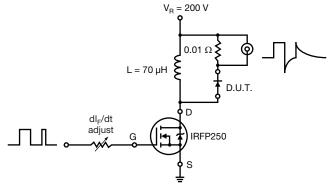
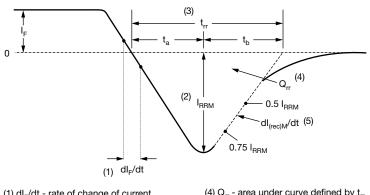


Fig. 11 - Reverse Recovery Parameter Test Circuit



- (1) dI_F/dt rate of change of current through zero crossing
- (2) I_{RRM} peak reverse recovery current
- (3) t_{rr} reverse recovery time measured from zero crossing point of negative going I_F to point where a line passing through 0.75 I_{RRM} and 0.50 I_{RRM} extrapolated to zero current.

(4) Q _{rr} - area	under curve defined by t _{rr}
and I _{RRM}	

$$Q_{rr} = \frac{t_{rr} \times I_{RRM}}{2}$$

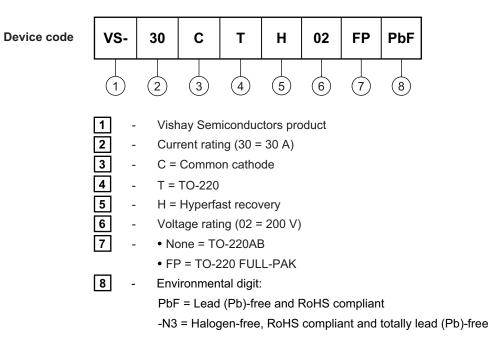
- (5) dI_{(rec)M}/dt peak rate of change of current during $t_{\rm b}$ portion of $t_{\rm rr}$
- Fig. 12 Reverse Recovery Waveform and Definitions

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ORDERING INFORMATION TABLE

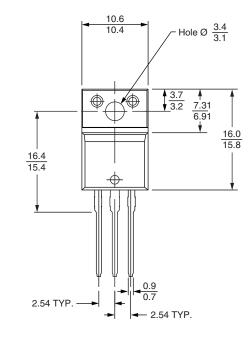


ORDERING INFORMATION (Example)						
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION			
VS-20CTH03PbF	50	1000	Antistatic plastic tube			
VS-20CTH03-N3	50	1000	Antistatic plastic tube			
VS-20CTH03FPPbF	50	1000	Antistatic plastic tube			
VS-20CTH03FP-N3	50	1000	Antistatic plastic tube			

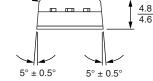
LINKS TO RELATED DOCUMENTS				
Dimensions	TO-220AB	www.vishay.com/doc?95222		
Dimensions	TO-220FP	www.vishay.com/doc?95072		
	TO-220ABPbF	www.vishay.com/doc?95225		
Part marking information	TO-220AB-N3	www.vishay.com/doc?95028		
Part marking information	TO-220FPPbF	www.vishay.com/doc?95069		
	TO-220FP-N3	www.vishay.com/doc?95456		



DIMENSIONS in millimeters

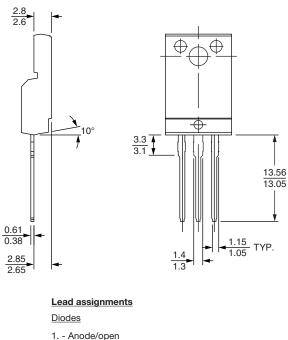


R 0.7 R 0.5 (2 places)





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2. - Cathode

3. - Anode

Conforms to JEDEC outline TO-220 FULL-PAK



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TO-220AB

DIMENSIONS in millimeters and inches





.ead	assignments

Diodes

1. - Anode/open 2. - Cathode 3. - Anode

SYMBOL	MILLIN	IETERS	INCHES		NOTES
STMBOL	MIN.	MAX.	MIN.	MAX.	NOTES
А	4.25	4.65	0.167	0.183	
A1	1.14	1.40	0.045	0.055	
A2	2.56	2.92	0.101	0.115	
b	0.69	1.01	0.027	0.040	
b1	0.38	0.97	0.015	0.038	4
b2	1.20	1.73	0.047	0.068	
b3	1.14	1.73	0.045	0.068	4
С	0.36	0.61	0.014	0.024	
c1	0.36	0.56	0.014	0.022	4
D	14.85	15.25	0.585	0.600	3
D1	8.38	9.02	0.330	0.355	
D2	11.68	12.88	0.460	0.507	6

Notes

- ⁽¹⁾ Dimensioning and tolerancing as per ASME Y14.5M-1994
- ⁽²⁾ Lead dimension and finish uncontrolled in L1
- ⁽³⁾ Dimension D, D1 and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body
- $^{\left(4\right) }$ Dimension b1, b3 and c1 apply to base metal only
- (5) Controlling dimensions: inches
- (6) Thermal pad contour optional within dimensions E, H1, D2 and E1

MILLIMETERS INCHES SYMBOL NOTES MIN. MAX. MIN. MAX. 10.51 0.414 10.11 0.398 3,6 Е E1 6.86 8.89 0.270 0.350 6 E2 0.76 0.030 7 --2.41 2.67 0.095 0.105 е 0.208 e1 4.88 5.28 0.192 H1 6.09 6.48 0.240 0.255 6,7 13.52 14.02 0.532 0.552 L L1 3.32 3.82 0.131 0.150 2 ØΡ 3.54 3.73 0.139 0.147 2.60 0.102 Q 3.00 0.118 90° to 93° 90° to 93° θ

Conforms to JEDEC outline TO-220AB

- (7) Dimensions E2 x H1 define a zone where stamping and singulation irregularities are allowed
- (8) Outline conforms to JEDEC TO-220, except A2 (maximum) and D2 (minimum) where dimensions are derived from the actual package outline



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